Microwave and THz sensing using slab-pair-based metamaterials

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Abstract

In this work the sensing capability of an artificial magnetic metamaterial based on pairs of metal slabs is demonstrated, both theoretically and experimentally, in the microwave regime. The demonstration is based on transmission measurements and simulations monitoring the shift of the magnetic resonance frequency as one changes a thin dielectric layer placed between the slabs of the pairs. Strong dependence of the magnetic resonance frequency on both the permittivity and the thickness of the dielectric layer under detection was observed. The sensitivity to the dielectrics’ permittivity (ε) is larger for dielectrics of low ε values, which makes the approach suitable for sensing organic materials also in the THz regime. The capability of our approach for THz sensing is also demonstrated through simulations.

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1. Introduction

Metamaterials have attracted intense research attention in recent years, due to their unique response to electromagnetic radiation and the possibility of engineering their electromagnetic properties to a much greater extent than what is possible in natural materials, and to achieve unusual and unique properties, such as optical magnetism, negative index of refraction [1] etc., enabling many unique applications, like perfect lensing [2], invisibility cloaks [2,3], etc.

Sensing could be listed as one of the areas where metamaterials offer revolutionary advancements, as stated in Refs. [4,5]. It has been proposed that metamaterials can be used in microwaves, e.g. for evaluation of dielectric materials [6], in the visible region, e.g. for the detection of biomolecules [7,8], and the measurement of gas concentrations [9,10], as well as in the monitoring of chemical reactions [11].

Microwaves are frequently used in sensing applications, e.g. in medical and aerospace industries, offering over traditional sensors many advantages, such as rapid, nondestructive, precise, and fully automated measurement which can be made in a laboratory or online. They permit relatively high spatial resolutions compared to other techniques and they do not require physical contact with the processed material, and still respond to the presence or absence of an object of interest [6]. Furthermore, microwave sensing techniques are relatively inexpensive and do not require extensive data analysis [6].

One of the most common metamaterial elements which has been widely demonstrated in microwaves is the split ring resonator (SRR), which was first proposed in 1999 [12]. SRR consists of a metallic ring with a split (or more than one co-centric rings with splits) on a dielectric substrate. The loop-like currents in the ring (excited by an incident EM wave) make it act as an inductor, while the split, where opposite charges are accumulated, acts as a capacitor [13–14], making the system behave as an effective inductor–capacitor (LC) circuit, showing a resonant electromagnetic response at a frequency \( f_0 = 1/\sqrt{LC} \). SRR has been extensively studied for its sensing capabilities in microwaves; it has been observed to have a significant sensing feature for different kinds of materials, such as bioassays [15], photoresist AZ9260 [16], liquids and their contaminations [17].

In each of the above cases, the capacitance of the SRR structures is changed by adding the substance of interest to the SRR, mainly in the SRR split/splits, giving a shift to the resonant frequency, detectable in simple transmission measurements. However, since a significant amount of electric field at the SRR split is located in the substrate [18], the capacitance of the structure cannot be highly affected by the substance under detection and it is mainly affected by the permittivity of the...
substrate dielectrics [18]. In terms of practical applications, this limits the utility of the SRR as a sensing device [19].

An alternative metamaterial structure that seems to be more suitable for microwave and THz sensing applications is a pair of slabs (see Fig. 1) [20], which, similar to the SRR, exhibits a resonant magnetic response (resonant magnetic moment) coming from loop-like currents. The structure has certain advantages over the SRR, due to its simplicity in fabrication and the ability to exhibit a resonant and negative permeability response for incidence normal to the plane of the pairs, and thus using just a monolayer of slab pairs.

The advantage of the slab-pair structure over the SRR regarding sensing applications is based on the fact that for relatively wide slabs (see Fig. 1) the electric field at the capacitive areas of the structure is entirely confined between the slabs and thus it is very strongly affected by the permittivity of the material located between the slabs. This property, combined with the easiness in the fabrication and handling of microwave (mm-size) slabs, and thus the possibility to easily insert various materials between the slabs, offers a great approach to accurately evaluate the electrical permittivity of the material between the slabs and thus to detect small changes in this permittivity.

In this work we use the above mentioned approach to demonstrate (both theoretically and experimentally) the sensing capability of slab-pair systems. Inserting various dielectric materials between the slabs of the pair, we show that one can accurately estimate the permittivity of those materials, detecting even very small changes in this permittivity, ϵ. Our current experimental data concern structures operating in the frequency range 7–16 GHz; the sensing approach and structures though (with proper scaling), as shown by simulations, can be applied equally well in far infrared and THz regimes, with only limitations being the ones stemming from the practical realization of the device.

2. Experimental data and numerical simulations

The slab-pair structures employed in the present study are made of square slabs (see Fig. 1), offering the advantage of isotropy in the E–H plane, and thus of insensitivity on the incident wave polarization. The slabs are assembled as shown in Fig. 1:

![Fig. 1. Schematic of the slab-pair’s structure. A magnification of one unit cell of the slab-pair’s structure (red shaded area) is presented. E, H, and k correspond to electric field, magnetic field, and wave vector, respectively. aE and aH (≈9.5 mm) are the size of the unit cell along E and H directions, respectively. l=7 mm and w=7 mm are the length and the width of the metallic slabs (gray color), respectively, while d corresponds to the thickness of the materials of interest (blue color), placed between the two FR-4 boards (yellow color). (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)](image)

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3. Results and discussion

As has been already reported [21,22], the electromagnetic properties of slab pair metamaterials can be explained using equivalent inductor–capacitor (LC) circuits. For wide slabs (large w) as in our case (see Fig. 1), the inductance of the system can be approximately calculated in a similar way as in a solenoid, given by

\[
L \approx \frac{\mu_0(d+2d_l)}{w}
\]

(1)

where l and w are the length and the width of the slabs, respectively (in our case l=w), and d+2d_l is the thickness of the regime between the two metal elements of the pair (see Fig. 1; the permeability of both layers is assumed to be μ0).

<table>
<thead>
<tr>
<th>Material (0.5 mm)</th>
<th>ɛ</th>
<th>Magn. resonant frequency (GHz)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Air</td>
<td>1.00</td>
<td>14.17</td>
</tr>
<tr>
<td>LDPE</td>
<td>2.28</td>
<td>11.88</td>
</tr>
<tr>
<td>FR-4</td>
<td>3.80</td>
<td>11.05</td>
</tr>
<tr>
<td>Silicon</td>
<td>11.90</td>
<td>10.38</td>
</tr>
</tbody>
</table>

* For the evaluation of the coefficients A1 and B1 of Eq. (4) the materials used are air and FR-4.
Furthermore, the total capacitance $C$ of the slab-pair structure can be approximated with that of two, in-series connected, parallel plate capacitors of relevant lengths $c_1 l$, $w$, and $(d+2t_0)$ along the $E$, $H$ and $k$ directions (see Fig. 1), respectively ($c_1$ is a numerical factor in the range $1/4 \leq c_1 \leq 1/5$, as can be concluded from electric field plots); thus $C$ can be written as

$$C \approx \varepsilon_0 \varepsilon_{\text{eff}} \frac{w c_1 l}{2 (d + 2 t_0)}$$

(2)

In Eq. (2) $\varepsilon_0$ is the free-space permittivity and $\varepsilon_{\text{eff}}$ is the relative permittivity of the material between the slabs, which in our case is the effective relative permittivity of the layered system formed by the dielectric boards supporting the metallic slabs, the material under sensing, and air (if the material under sensing does not fill all the space between the metallic elements of the pair). This permittivity can be calculated as [23]

$$\varepsilon_{\text{eff}} = \left( \frac{\sum_{n=1}^{n} \frac{d_m}{\varepsilon_m d_{\text{tot}}}}{n+1} \right)^{-1} = \frac{1}{\varepsilon_{\text{tot}}} \left( \frac{2 \varepsilon_{\text{air}}}{\varepsilon_{\text{air}} + \varepsilon_{\text{tot}}} \right)$$

(3)

where $\varepsilon_m$, and $d_m$ are respectively the relative permittivity and the thickness of each layer of the layered material, and $d_{\text{tot}}$ is the total distance between the metal slabs. In our case, where the slabs are printed on FR-4 boards of thickness $t_0 = 0.6$ mm, $d_1$ is the thickness of the material of interest and $\varepsilon_0$ its relative permittivity.

Taking into account the above equations, one can obtain the magnetic-resonance frequency of the system as

$$f_{\mu} = \frac{\omega_{\mu}}{2\pi} = \frac{1}{2 \pi \sqrt{LC}} = \frac{1}{\sqrt{2 c_1 l \sqrt{\varepsilon_{\text{eff}}}}} = \frac{A}{\sqrt{\varepsilon_{\text{eff}}}} = \sqrt{A \frac{B_1}{\varepsilon_0}}$$

(4)

where $c$ is the free space light velocity, $A = c / \pi l \sqrt{2 c_1}$, while the constants $A_1$ and $B_1$ include the geometry and material parameters which do not depend on $\varepsilon_0$.

From Eq. (4) one can notice that the magnetic-resonance frequency of the slab-pair design is strongly dependent on the dielectric properties of the material between the slabs, especially if this material is of low permittivity value, lower than the permittivity of the FR-4 boards where the metal slabs are printed. This sensitivity is confirmed by the detailed experimental and numerical data presented in Fig. 2.

Fig. 2 shows the simulation (upper panel; solid lines) and experimental results (lower panel; dotted lines) regarding the transmission coefficient of the four materials listed in Table 1, for thickness $d = d_0 = 0.5$ mm. Aside from the very good agreement between simulations and experiments, one can observe in Fig. 2 a quite large shift of the magnetic resonance to lower frequencies as the permittivity of the dielectric between the slab-pairs changes from 1.0 (air) to 11.90 (silicon). The relative shift is larger for materials of lower permittivity, as suggested by Eq. (4).

Indeed, the last expression in Eq. (4) can be used for a quite accurate evaluation of the electrical permittivity of the material between the slabs if the values of the constants $A_1$ and $B_1$ for each geometric configuration are available (these values can be calculated by considering the transmission for two known materials). For the configuration of Fig. 2 and using the calculation of $A_1$ and $B_1$, the magnetic resonance frequency for air ($f_{\mu_{\text{air}}}=14.17 \text{ GHz}$) and FR-4 ($f_{\mu_{\text{FR-4}}}=11.05 \text{ GHz}$), one can find $A_1=94.00 \text{ GHz}^2$ and $B_1=106.789 \text{ GHz}^2$. For this choice of $A_1$ and $B_1$, the last expression of Eq. (4) can reproduce very well the numerical and experimental $f_{\mu}$ vs $\varepsilon_0$ data, especially for materials of low permittivity values (lower than that of the dielectric (FR-4) board on which the metallic pair is printed), as shown in Fig. 3 and indicated also by column 5 of Table 1.

Besides the quantitative power of the last expression in Eq. (4), the preceding relation $f_{\mu} = A / \sqrt{\varepsilon_{\text{eff}}}$ of Eq. (4) in combination with Eq. (3) offers a nice qualitative expression of the magnetic resonance frequency dependence on $\varepsilon_0$, which can be used to optimize the sensing design. These equations suggest that an easy way to enlarge the sensitivity of our design and to achieve high sensitivity in a broader permittivity range is to print the slabs on higher-index dielectrics (i.e. of larger $\varepsilon_0$), since $\varepsilon_{\text{eff}}$ is more strongly influenced by the lower-index material of the layered structure. Indeed, for slabs of the same geometrical features as those of Fig. 2 but printed on silicon boards ($\varepsilon_{\text{air}}=11.9$), the sensitivity of the structure becomes larger than that shown in Fig. 2 and is maintained for materials of higher $\varepsilon_0$, as shown by related simulations (not shown here). For example the difference $\Delta f_f_{\mu}=f_{\mu_{\varepsilon_0=6}}-f_{\mu_{\varepsilon_0=5}}$ which for the FR-4 board case is $0.15 \text{ GHz}$ becomes $-0.25 \text{ GHz}$ for the Si case.

As Eqs. (3) and (4) suggest, the magnetic resonance frequency of our structure will depend also on the thickness of the material under sensing. This dependence is examined in Figs. 4 and 5.

Fig. 4 shows the simulated transmission as a function of frequency for the geometry of Fig. 2, but for the space between the slabs (of thickness $d = 0.5$ mm) only partially filled with LDPE;

![Fig. 2. Simulation (upper panel; solid lines) and experimental results (lower panel; dotted lines) regarding the transmission of a slab pair structure enclosing several materials with a thickness of 0.5 mm and different dielectric constants, already described in Table 1.](image1)

![Fig. 3. Magnetic-resonance frequency ($f_{\mu}$) of the system of paired slabs vs the relative permittivity of the material under sensing ($\varepsilon_0$), calculated using Eq. (4) with $A_1=94.00 \text{ GHz}^2$, and $B_1=106.789 \text{ GHz}^2$ (black line). Red dots correspond to the values of resonance frequency obtained through transmission simulations.](image2)
the rest is air. From Fig. 4 one can see that even a very thin layer of LPDE, of thickness \(d = 0.1\) mm, can lead to a resonance frequency shift as large as 0.5 GHz, indicating the large sensitivity of our design.

Fig. 5 illustrates the simulated and the measured transmission for a structure where the thickness of the dielectric material under detection, \(d = d_a\), varies between 0.5 mm (as Fig. 2) and 1.5 mm. The dielectric materials here are LDPE and air and they fill all the available space between the slabs. Comparing the resonance frequency difference between the two dielectric materials under detection, we see that this difference, which is \(\sim 2.3\) GHz for \(d = 0.5\) mm (solid lines), becomes \(\sim 3.7\) GHz for \(d = d_a = 1.5\) mm (dotted lines), showing that the approach becomes even more sensitive if one can provide thicker layers of the material under detection. The dependence of the magnetic resonance frequency on the thickness of the material under detection can be qualitatively concluded by Eq. (4) in combination with Eq. (3), as the \(f_{	ext{res}}\) of the layered structure between the metallic slabs is reduced if one increases the thickness of the spacer material.

The sensitivity of our sensing approach, especially for dielectrics of low permittivity values, makes it appropriate for operation in THz and IR regimes for the sensing of biomolecular and/or organic materials. This capability of the approach is illustrated in Fig. 6, where we present transmission simulations for a slab-pair system of \(\mu\)m scale, sensing low permittivity dielectrics, of \(\varepsilon\) between 1 and 3. The pair is now printed on glass substrate \((\varepsilon_b = 3.9)\) of thickness 1 \(\mu\)m, leaving a space \(d = d_a = 0.5\) \(\mu\)m between the slabs for the material under detection.

From Fig. 6 one can see that for dielectric materials of \(\varepsilon\) between 1 and 1.5 there is a magnetic resonance shift, \(\Delta f_m\), as large as 0.5 THz, indicating the suitability of our approach for sensing applications in the THz and far-IR regimes. As discussed in the microwave case above, the sensitivity of the design can become even higher if the slabs are printed on Si or GaAs boards. Finally, we have to mention here that slab-pair-based systems can be easily fabricated using UV lithography and characterized using THz time domain spectroscopy showing signal to noise ratios as high as 1000 (corresponding to \(\sim 30\) dB transmission).

4. Conclusions

We have studied the sensing capability of a metamaterial structure made of pairs of metal slabs, in both microwave and THz regimes. The microwave study has been done by both measuring and simulating the shift of the magnetic resonance frequency as one varies the electrical permittivity and thickness of a dielectric layer placed between the slabs of the pairs. The agreement between measurements and simulations is very good. Our results, showing a larger sensitivity for lower-index dielectrics, can be qualitatively predicted using an LC circuit description of the slab-pair structure. This description can lead also to conditions for increasing the sensitivity of our sensing approach and design. Finally, simulations concerning \(\mu\)m-scale slab-pair-based systems show that our sensing design and approach can be easily applied in the THz regime.

4. Conclusions
Acknowledgments

Authors would like to acknowledge the support by EU, through Projects ENSEMBLE and NIMNIL, and the COST actions MP0702 and MP0803. Work at Ames Laboratory was partially supported by the Department of Energy (Basic Energy Sciences) under Contract no. DE-AC02–07CH11358 (computational studies). Fruitful discussions with Dr. Thomas Koschny are also acknowledged.

References